74LVC2G125

Dual bus buffer/line driver; 3-state

Rev. 19 — 12 August 2024

Product data sheet

1. General description

The 74LVC2G125 is a dual buffer/line driver with 3-state outputs controlled by the output enable inputs (nOE). Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- I_{OFF} circuitry provides partial Power-down mode operation
- ±24 mA output drive (V_{CC} = 3.0 V)
- CMOS low-power consumption
- Latch-up performance exceeds 250 mA
- · Direct interface with TTL levels
- Overvoltage tolerant inputs to 5.5 V
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
 JESD36 (4.5 V to 5.5 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



Dual bus buffer/line driver; 3-state

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | | |
|--------------|-------------------|--------|---|----------|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | |
| 74LVC2G125DP | -40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm | SOT505-2 | | | | |
| 74LVC2G125DC | -40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm | SOT765-1 | | | | |
| 74LVC2G125GT | -40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm | SOT833-1 | | | | |
| 74LVC2G125GN | -40 °C to +125 °C | XSON8 | extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm | SOT1116 | | | | |
| 74LVC2G125GS | -40 °C to +125 °C | XSON8 | extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm | SOT1203 | | | | |

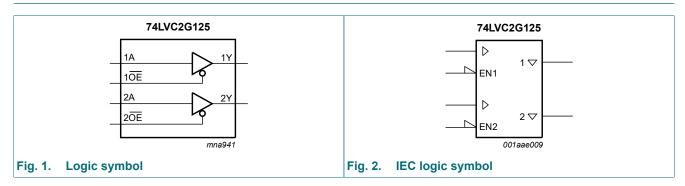
4. Marking

Table 2. Marking codes

| Table 21 marking codes | | | | | |
|------------------------|------------------|--|--|--|--|
| Type number | Marking code [1] | | | | |
| 74LVC2G125DP | V25 | | | | |
| 74LVC2G125DC | V25 | | | | |
| 74LVC2G125GT | V25 | | | | |
| 74LVC2G125GN | VM | | | | |
| 74LVC2G125GS | VM | | | | |

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

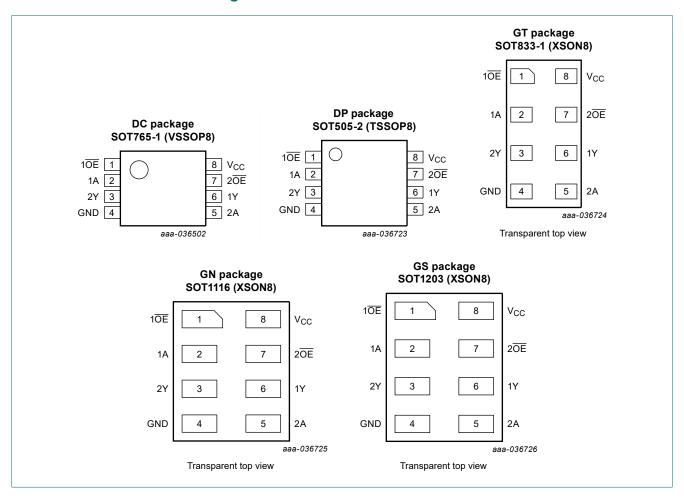
5. Functional diagram



Dual bus buffer/line driver; 3-state

6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------------------------|------|----------------------------------|
| 1 OE , 2 OE | 1, 7 | output enable input (active LOW) |
| 1A, 2A | 2, 5 | data input |
| GND | 4 | ground (0 V) |
| 1Y, 2Y | 6, 3 | data output |
| V _{CC} | 8 | supply voltage |

Dual bus buffer/line driver; 3-state

7. Functional description

Table 4. Function table

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; X = don't care; Z = high-impedance OFF-state.}$

| | Input | Output |
|-----|-------|--------|
| nOE | nA | nY |
| L | L | L |
| L | Н | Н |
| Н | X | Z |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--|------|-----------------------|------|
| V _{CC} | supply voltage | | -0.5 | +6.5 | V |
| I _{IK} | input clamping current | V _I < 0 V | -50 | - | mA |
| VI | input voltage | [1] | -0.5 | +6.5 | V |
| I _{OK} | output clamping current | $V_O > V_{CC}$ or $V_O < 0$ V | - | ±50 | mA |
| Vo | output voltage | Enable mode [1] | -0.5 | V _{CC} + 0.5 | V |
| | | Disable mode [1] | -0.5 | +6.5 | V |
| | | Power-down mode; V _{CC} = 0 V [1] | -0.5 | +6.5 | V |
| I _O | output current | $V_O = 0 V \text{ to } V_{CC}$ | - | ±50 | mA |
| I _{CC} | supply current | | - | 100 | mA |
| I_{GND} | ground current | | -100 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2] | - | 250 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|---|------|-----------------|------|
| V_{CC} | supply voltage | | 1.65 | 5.5 | V |
| VI | input voltage | | 0 | 5.5 | V |
| V _O | output voltage | V _{CC} = 1.65 V to 5.5 V; Enable mode | 0 | V _{CC} | V |
| | | V _{CC} = 1.65 V to 5.5 V; Disable mode | 0 | 5.5 | V |
| | | V _{CC} = 0 V; Power-down mode | 0 | 5.5 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 1.65 V to 2.7 V | - | 20 | ns/V |
| | | V _{CC} = 2.7 V to 5.5 V | - | 10 | ns/V |

^[2] For SOT505-2 (TSSOP8) package: Ptot derates linearly with 4.6 mW/K above 96 °C.

For SOT765-1 (VSSOP8) package: P_{tot} derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: Ptot derates linearly with 3.1 mW/K above 68 °C.

For SOT1116 (XSON8) package: Ptot derates linearly with 4.2 mW/K above 90 °C.

For SOT1203 (XSON8) package: P_{tot} derates linearly with 3.6 mW/K above 81 °C.

Dual bus buffer/line driver; 3-state

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|------------------|---------------------------|---|-----------------------|---------|---------------------|-----------------------|---------------------|------|
| | | | Min | Typ [1] | Max | Min | Max | |
| V _{IH} | HIGH-level | V _{CC} = 1.65 V to 1.95 V | 0.65V _{CC} | - | - | 0.65V _{CC} | - | V |
| | input voltage | V _{CC} = 2.3 V to 2.7 V | 1.7 | - | - | 1.7 | - | V |
| | | V _{CC} = 2.7 V to 3.6 V | 2.0 | - | - | 2.0 | - | V |
| | | V _{CC} = 4.5 V to 5.5 V | 0.7V _{CC} | - | - | 0.7V _{CC} | - | V |
| V _{IL} | LOW-level | V _{CC} = 1.65 V to 1.95 V | - | - | 0.35V _{CC} | - | 0.35V _{CC} | V |
| | input voltage | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | - | 0.7 | V |
| | | V _{CC} = 2.7 V to 3.6 V | - | - | 0.8 | - | 0.8 | V |
| | | V _{CC} = 4.5 V to 5.5 V | - | - | 0.3V _{CC} | - | 0.3V _{CC} | V |
| V _{OL} | LOW-level | $V_I = V_{IH}$ or V_{IL} | | | | | | |
| | output voltage | I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V | - | - | 0.1 | - | 0.1 | V |
| | | I _O = 4 mA; V _{CC} = 1.65 V | - | - | 0.45 | - | 0.70 | V |
| | | I _O = 8 mA; V _{CC} = 2.3 V | - | - | 0.3 | - | 0.45 | V |
| | | I _O = 12 mA; V _{CC} = 2.7 V | - | - | 0.4 | - | 0.60 | V |
| | | I _O = 24 mA; V _{CC} = 3.0 V | - | - | 0.55 | - | 0.80 | V |
| | | I _O = 32 mA; V _{CC} = 4.5 V | - | - | 0.55 | - | 0.80 | V |
| V _{OH} | HIGH-level | V _I = V _{IH} or V _{IL} | | | | | | |
| | output voltage | I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V | V _{CC} - 0.1 | - | - | V _{CC} - 0.1 | - | V |
| | | I _O = -4 mA; V _{CC} = 1.65 V | 1.2 | - | - | 0.95 | - | V |
| | | I_{O} = -8 mA; V_{CC} = 2.3 V | 1.9 | - | - | 1.7 | - | V |
| | | I _O = -12 mA; V _{CC} = 2.7 V | 2.2 | - | - | 1.9 | - | V |
| | | I _O = -24 mA; V _{CC} = 3.0 V | 2.3 | - | - | 2.0 | - | V |
| | | I _O = -32 mA; V _{CC} = 4.5 V | 3.8 | - | - | 3.4 | - | V |
| I _I | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | ±0.1 | ±1 | - | ±1 | μΑ |
| l _{OZ} | OFF-state output current | $V_I = V_{IH}$ or V_{IL} ; $V_O = 5.5$ V or GND; $V_{CC} = 3.6$ V | - | ±0.1 | ±2 | - | ±2 | μΑ |
| I _{OFF} | power-off leakage current | V_{I} or $V_{O} = 5.5 \text{ V}$; $V_{CC} = 0 \text{ V}$ | - | ±0.1 | ±2 | - | ±2 | μΑ |
| I _{CC} | supply current | V _I = 5.5 V or GND; V _{CC} = 1.65 V to 5.5 V; I _O = 0 A | - | 0.1 | 4 | - | 4 | μΑ |
| ΔI _{CC} | additional supply current | per pin; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 2.3 \text{ V}$ to 5.5 V | - | 5 | 500 | - | 500 | μΑ |
| Cı | input capacitance | | - | 2 | - | - | - | pF |

^[1] Typical values are measured at V_{CC} = 3.3 V and at T_{amb} = 25 °C.

Dual bus buffer/line driver; 3-state

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground 0 V); for test circuit see Fig. 5.

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|------------------|--------------|---|------------------|---------|------|-------------------|------|------|
| | | | Min | Typ [1] | Max | Min | Max | |
| t _{pd} | propagation | nA to nY; see Fig. 3 [2] | | | | | | |
| | delay | V _{CC} = 1.65 V to 1.95 V | 1.0 | 3.7 | 9.1 | 1.0 | 11.4 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 0.5 | 2.5 | 4.8 | 0.5 | 6.0 | ns |
| | | V _{CC} = 2.7 V | 1.0 | 2.7 | 4.8 | 1.0 | 6.0 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 0.5 | 2.3 | 4.3 | 0.5 | 5.5 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 0.5 | 1.9 | 3.7 | 0.5 | 4.6 | ns |
| t _{en} | enable time | nOE to nY; see Fig. 4 [3] | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.5 | 4.3 | 9.9 | 1.5 | 12.4 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.0 | 2.8 | 5.6 | 1.0 | 7.0 | ns |
| | | V _{CC} = 2.7 V | 1.5 | 3.3 | 5.7 | 1.5 | 7.1 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 0.5 | 2.4 | 4.7 | 0.5 | 5.9 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 0.5 | 2.0 | 3.8 | 0.5 | 4.8 | ns |
| t _{dis} | disable time | nOE to nY; see Fig. 4 [4] | | | | | | |
| | | V _{CC} = 1.65 V to 1.95 V | 1.0 | 3.5 | 11.6 | 1.0 | 14.1 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 0.5 | 1.8 | 5.8 | 0.5 | 7.6 | ns |
| | | V _{CC} = 2.7 V | 1.0 | 2.7 | 4.8 | 1.0 | 6.2 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 2.7 | 4.6 | 1.0 | 5.9 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 0.5 | 1.8 | 3.4 | 0.5 | 4.6 | ns |
| C _{PD} | 1: | per buffer; V_I = GND to V_{CC} [5] | | | | | | |
| | capacitance | output enabled | - | 18 | - | - | - | pF |
| | | output disabled | - | 5 | - | - | - | pF |

^[1] Typical values are measured at nominal V_{CC} and at T_{amb} = 25 °C.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

^[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

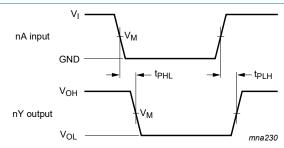
^[3] t_{en} is the same as t_{PZH} and t_{PZL} .

^[4] t_{dis} is the same as t_{PLZ} and t_{PHZ} .

^[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

Dual bus buffer/line driver; 3-state

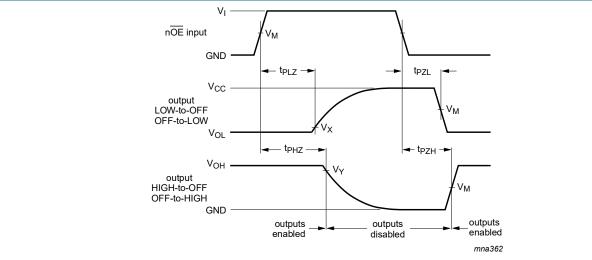
11.1. Waveforms and test circuit



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 3. Propagation delay input (nA) to output (nY)



Measurement points are given in Table 9.

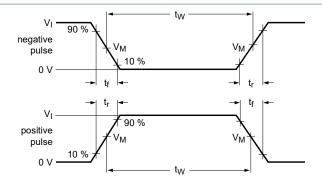
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

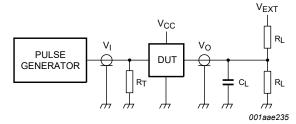
Fig. 4. 3-state output enable and disable times

Table 9. Measurement points

| Supply voltage | Input | Output | | | | |
|------------------|--------------------|--------------------|--------------------------|--------------------------|--|--|
| V _{CC} | V _M | V _M | V _X | V _Y | | |
| 1.65 V to 1.95 V | 0.5V _{CC} | 0.5V _{CC} | V _{OL} + 0.15 V | V _{OH} - 0.15 V | | |
| 2.3 V to 2.7 V | 0.5V _{CC} | 0.5V _{CC} | V _{OL} + 0.15 V | V _{OH} - 0.15 V | | |
| 2.7 V | 1.5 V | 1.5 V | V _{OL} + 0.3 V | V _{OH} - 0.3 V | | |
| 3.0 V to 3.6 V | 1.5 V | 1.5 V | V _{OL} + 0.3 V | V _{OH} - 0.3 V | | |
| 4.5 V to 5.5 V | 0.5V _{CC} | 0.5V _{CC} | V _{OL} + 0.3 V | V _{OH} - 0.3 V | | |

Dual bus buffer/line driver; 3-state





Test data is given in <u>Table 10</u>.

Definitions for test circuit:

R_L = Load resistor;

C_L = Load capacitance including jig and probe capacitance;

 R_{T} = Termination resistance should be equal to output impedance Z_{o} of the pulse generator;

V_{EXT} = Test voltage for switching times.

Fig. 5. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage | Input | | Load | Load | | V _{EXT} | | |
|------------------|-----------------|---------------------------------|-------|----------------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| V _{CC} | VI | t _r , t _f | CL | R _L | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | |
| 1.65 V to 1.95 V | V _{CC} | ≤ 2.0 ns | 30 pF | 1 kΩ | open | GND | 2V _{CC} | |
| 2.3 V to 2.7 V | V _{CC} | ≤ 2.0 ns | 30 pF | 500 Ω | open | GND | 2V _{CC} | |
| 2.7 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | 6 V | |
| 3.0 V to 3.6 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | 6 V | |
| 4.5 V to 5.5 V | V _{CC} | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | 2V _{CC} | |

Dual bus buffer/line driver; 3-state

12. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

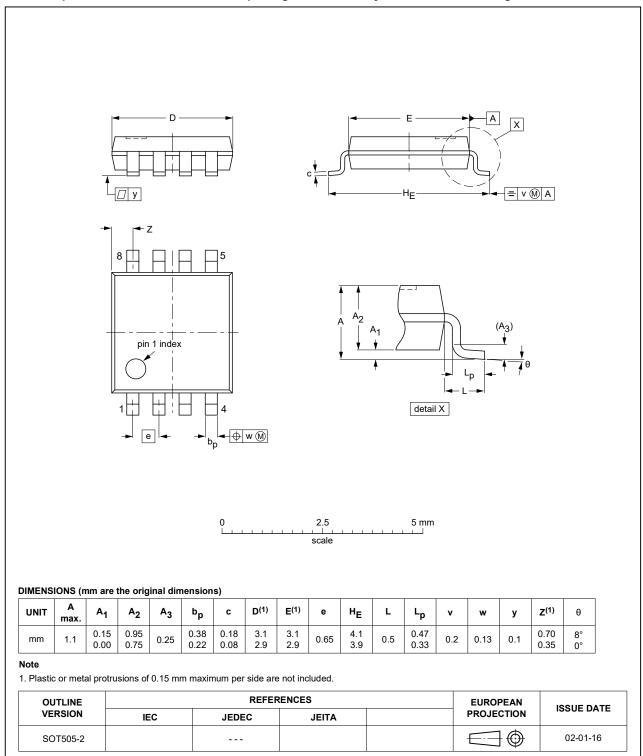


Fig. 6. Package outline SOT505-2 (TSSOP8)

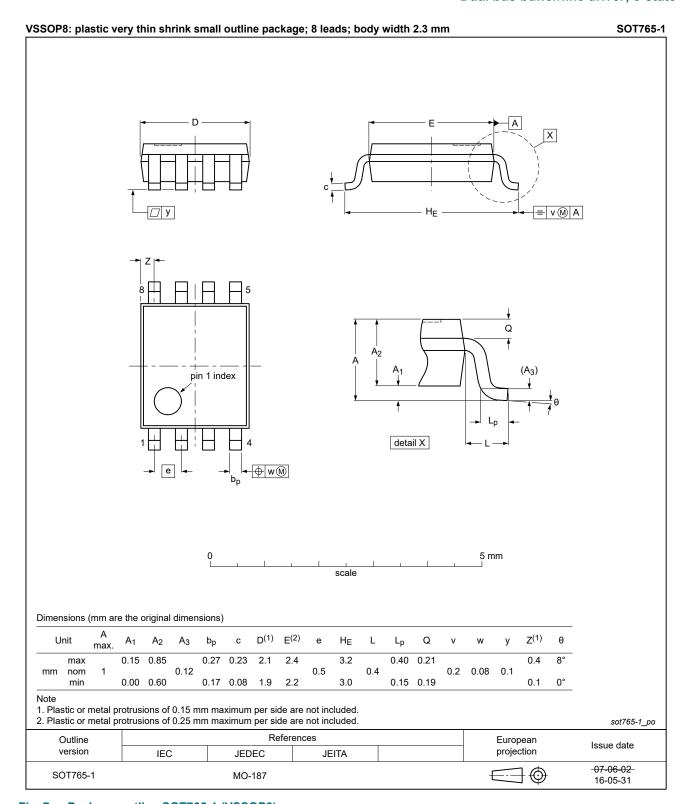


Fig. 7. Package outline SOT765-1 (VSSOP8)

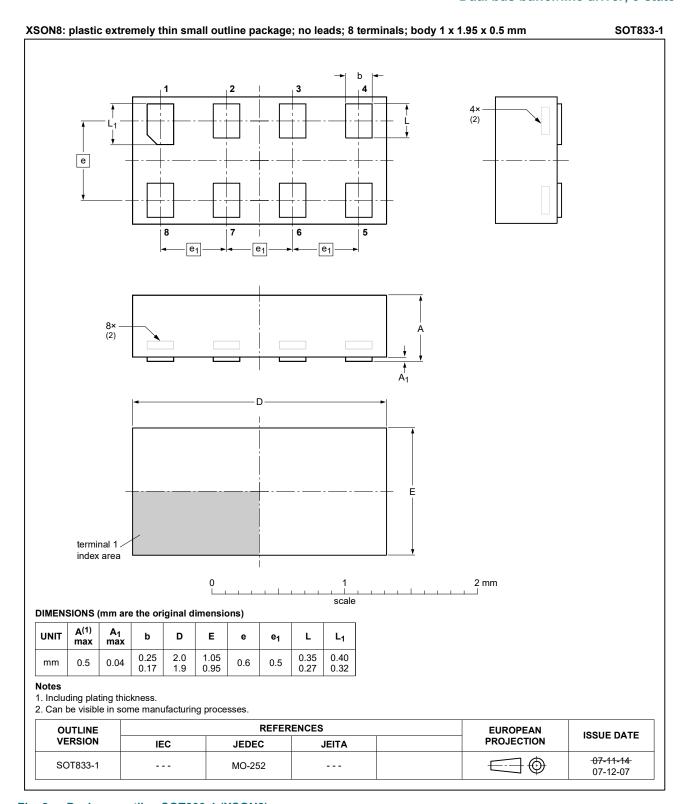


Fig. 8. Package outline SOT833-1 (XSON8)

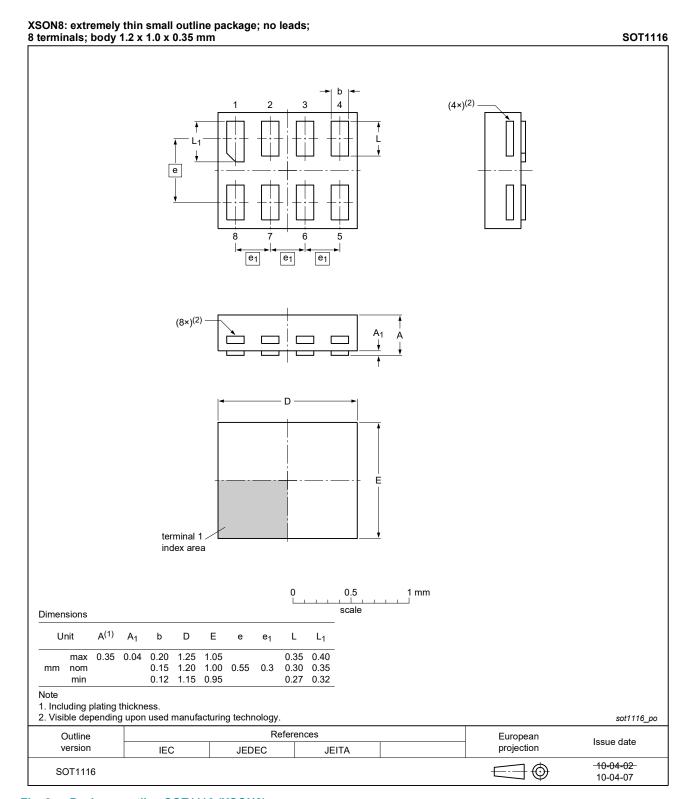


Fig. 9. Package outline SOT1116 (XSON8)

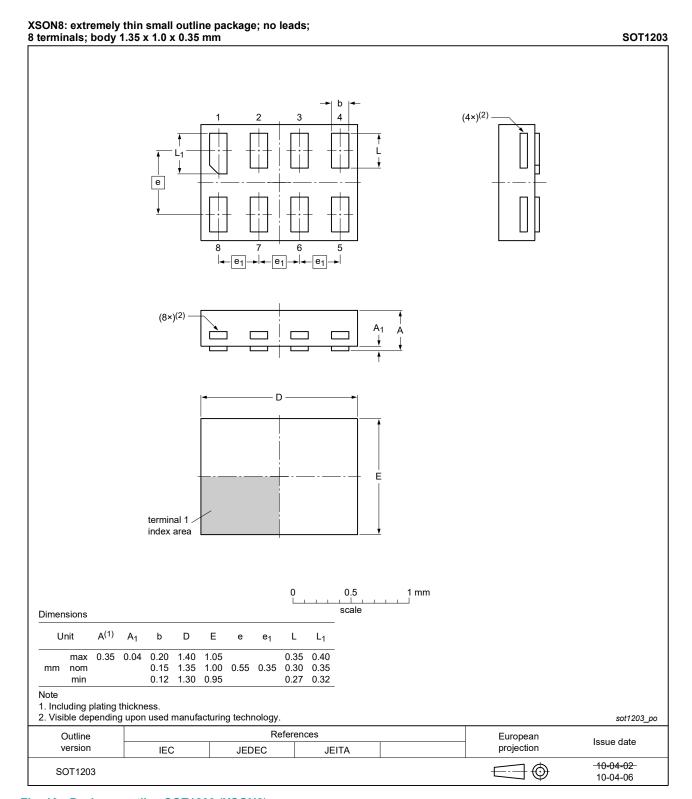


Fig. 10. Package outline SOT1203 (XSON8)

Dual bus buffer/line driver; 3-state

13. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|---|
| ANSI | American National Standards Institute |
| CDM | Charged Device Model |
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| ESDA | ElectroStatic Discharge Association |
| НВМ | Human Body Model |
| JEDEC | Joint Electron Device Engineering Council |
| TTL | Transistor-Transistor Logic |

14. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | | | |
|-----------------|---------------------------------|--|---------------------|----------------------------|--|--|--|--|
| 74LVC2G125 v.19 | 20240812 | Product data sheet | - | 74LVC2G125 v.18 | | | | |
| Modifications: | Type number | er 74LVC2G125GF (SOT1 | 089/XSON8) remo | oved. | | | | |
| 74LVC2G125 v.18 | 20230816 | 0230816 Product data sheet - 74LVC2G125 v.17 | | | | | | |
| Modifications: | Section 2: E | SD specification updated | according to the la | atest JEDEC standard. | | | | |
| 74LVC2G125 v.17 | 20210726 | Product data sheet | - | 74LVC2G125 v.16 | | | | |
| Modifications: | • <u>Section 1</u> a | er 74LVC2G125GM (SOTS nd <u>Section 2</u> updated. Derating values for P _{tot} tota | , | | | | | |
| 74LVC2G125 v.16 | 20180910 | Product data sheet | - | 74LVC2G125 v.15 | | | | |
| Modifications: | guidelines of Legal texts | Logar texts have been adapted to the new company frame where appropriate. | | | | | | |
| 74LVC2G125 v.15 | 20161215 | Product data sheet | - | 74LVC2G125 v.14 | | | | |
| Modifications: | • <u>Table 7</u> : The | e maximum limits for leaka | ge current and su | pply current have changed. | | | | |
| 74LVC2G125 v.14 | 20130329 | Product data sheet | - | 74LVC2G125 v.13 | | | | |
| Modifications: | For type nu | mber 74LVC2G125GD XS | ON8U has change | ed to XSON8. | | | | |
| 74LVC2G125 v.13 | 20120622 | Product data sheet | - | 74LVC2G125 v.12 | | | | |
| Modifications: | For type nu | mber 74LVC2G125GM the | SOT code has ch | nanged to SOT902-2. | | | | |
| 74LVC2G125 v.12 | 20111201 | Product data sheet | - | 74LVC2G125 v.11 | | | | |
| Modifications: | Legal page: | s updated. | | | | | | |
| 74LVC2G125 v.11 | 20100909 | Product data sheet | - | 74LVC2G125 v.10 | | | | |
| 74LVC2G125 v.10 | 20080611 | Product data sheet | - | 74LVC2G125 v.9 | | | | |
| 74LVC2G125 v.9 | 20080226 | Product data sheet | - | 74LVC2G125 v.8 | | | | |
| 74LVC2G125 v.8 | 20070907 | Product data sheet | - | 74LVC2G125 v.7 | | | | |
| 74LVC2G125 v.7 | 20060523 | Product data sheet | - | 74LVC2G125 v.6 | | | | |

Dual bus buffer/line driver; 3-state

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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| Product [short] data sheet | Production | This document contains the product specification. |

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Dual bus buffer/line driver; 3-state

Contents

| 1. | General description | 1 |
|-----|----------------------------------|------|
| 2. | Features and benefits | 1 |
| 3. | Ordering information | 2 |
| 4. | Marking | 2 |
| 5. | Functional diagram | 2 |
| 6. | Pinning information | 3 |
| 6.1 | . Pinning | 3 |
| 6.2 | Pin description | 3 |
| 7. | Functional description | 4 |
| 8. | Limiting values | 4 |
| 9. | Recommended operating conditions | 4 |
| 10. | Static characteristics | 5 |
| 11. | Dynamic characteristics | 6 |
| 11. | 1. Waveforms and test circuit | 7 |
| 12. | Package outline | 9 |
| 13. | Abbreviations | . 14 |
| 14. | Revision history | .14 |
| 15. | Legal information | .15 |
| | | |

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